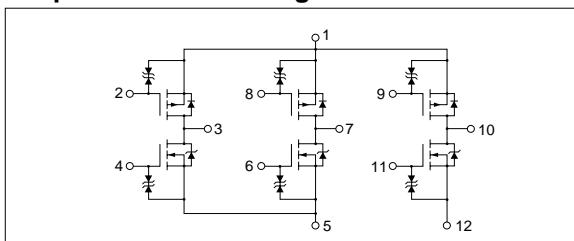


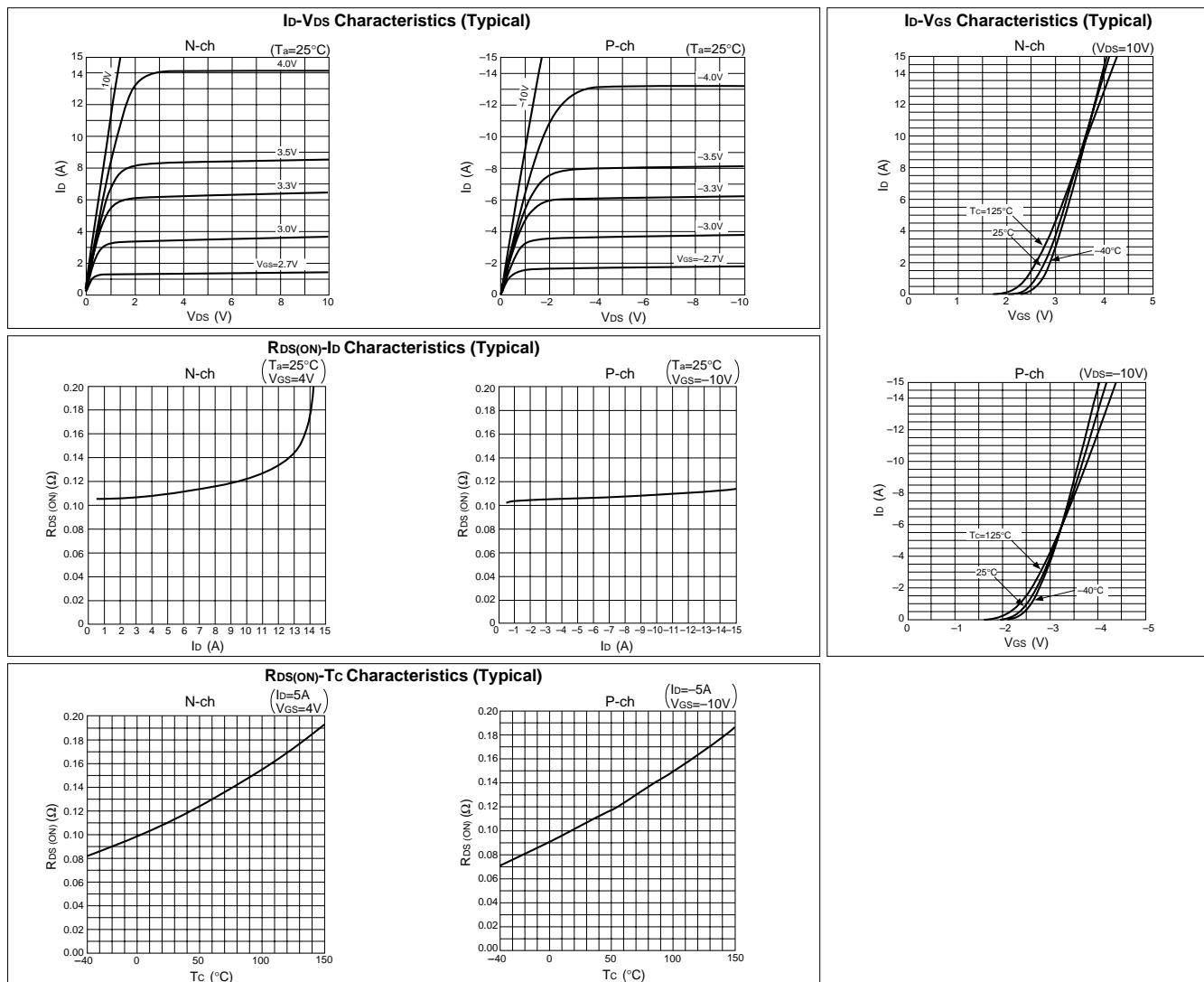
Absolute maximum ratings

Symbol	Ratings		(Ta=25°C)
	N channel	P channel	Unit
V _{DSS}	60	-60	V
V _{GSS}	±20	±20	V
I _D	10	-6	A
I _{D(pulse)}	15 (PW≤1ms, duty≤25%)	-15 (PW≤1ms, duty≤25%)	A
P _T	5 (Ta=25°C, with all circuits operating, without heatsink) 40 (Tc=25°C, with all circuits operating, with infinite heatsink)		W
θ _{j-a}	25 (Junction-Air, Ta=25°C, with all circuits operating)		°C/W
θ _{j-c}	3.125 (Junction-Case, Tc=25°C, with all circuits operating)		°C/W
V _{iso}	1000 (Between fin and lead pin, AC)		Vrms
T _{ch}	150		°C
T _{tsg}	-40 to +150		°C

Equivalent circuit diagram



Characteristic curves

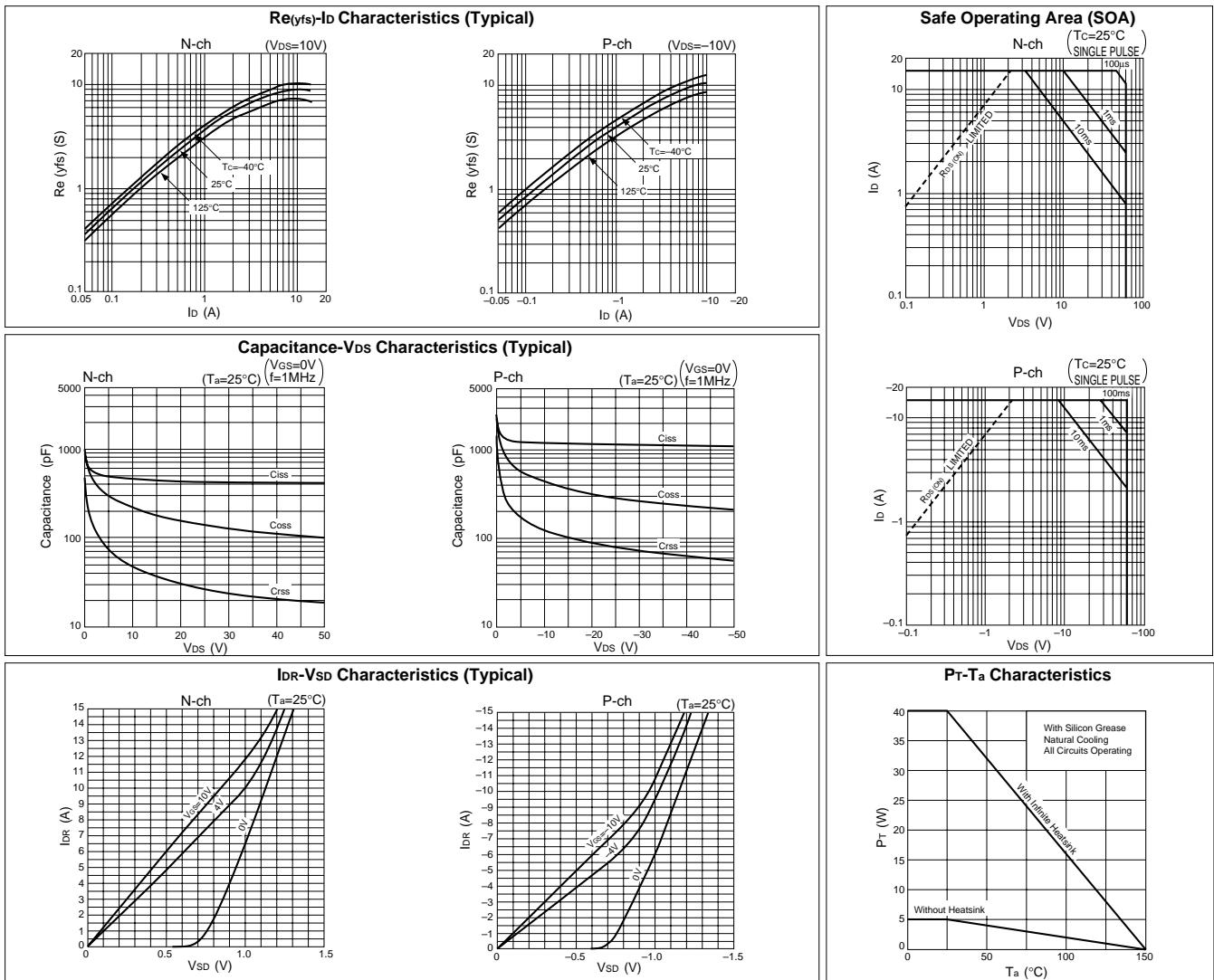


Electrical characteristics

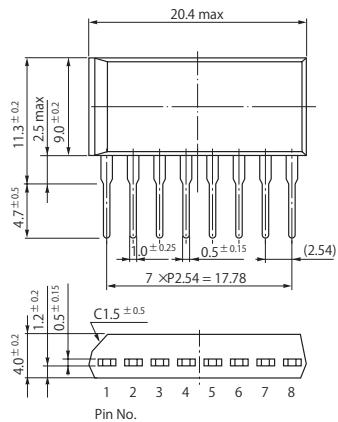
(Ta=25°C)

Symbol	N channel						P channel					
	Specification			Unit	Conditions	Specification			Unit	Conditions		
	min	typ	max			min	typ	max				
V(BR)DSS	60			V	Id=100µA, Vgs=0V	-60			V	Id=-100µA, Vgs=0V		
Igss			±10	µA	Vgs=±20V				µA	Vgs=±20V		
Isss			100	µA	Vds=60V, Vgs=0V				µA	Vds=−60V, Vgs=0V		
VTH	1.0		2.0	V	Vds=10V, Id=250µA	-1.0			V	Vds=−10V, Id=−250µA		
Re(yfs)		8		S	Vds=10V, Id=5A		8.7		S	Vds=−10V, Id=−5A		
RDS(ON)			0.14	Ω	Vgs=4V, Id=5A				0.14	Ω	Vgs=−10V, Id=−5A	
Ciss		460		pF	Vds=10V, f=1.0MHz, Vgs=0V		1200		pF	Vds=−10V, f=1.0MHz, Vgs=0V		
Coss		225		pF			440		pF			
Crss		50		pF			120		pF			
td(on)		25		ns	Id=5A, Vdd=20V, RL=4Ω, Vgs=5V, see Fig. 3 on page 16.		50		ns	Id=−5A, Vdd=20V, RL=4Ω, Vgs=−5V see Fig. 4 on page 16.		
tr		110		ns			170		ns			
td(off)		90		ns			180		ns			
tf		55		ns			100		ns			
VSD		1.15		V	Isd=10A, Vgs=0V		-1.25		V	Isd=−10A, Vgs=0V		
trr		75		ns	Isd=5A, Vgs=0V di/dt=100A/µs		100		ns	Isd=−5A, Vgs=0V di/dt=100A/µs		

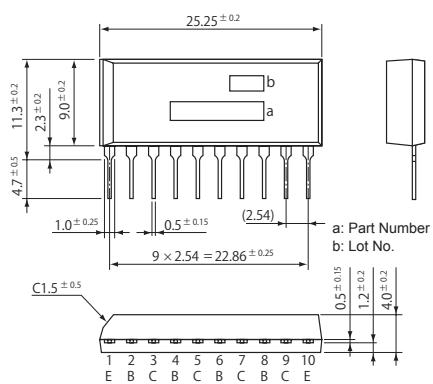
Characteristic curves



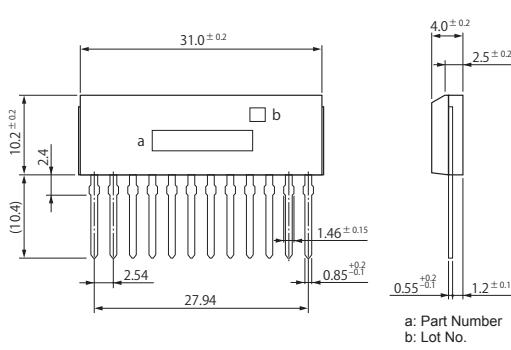
• SIP 8 (STA8Pin)



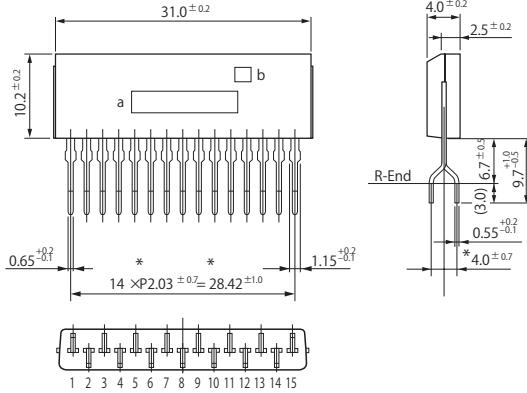
• SIP 10 (STA10Pin)



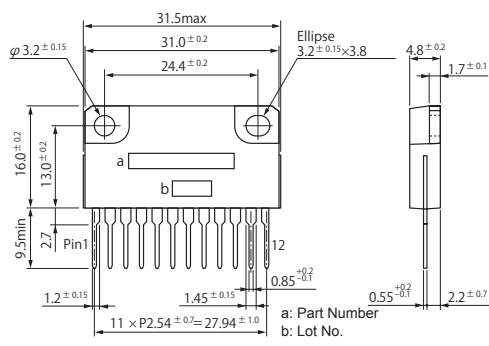
• SIP 12 (SMA12Pin)



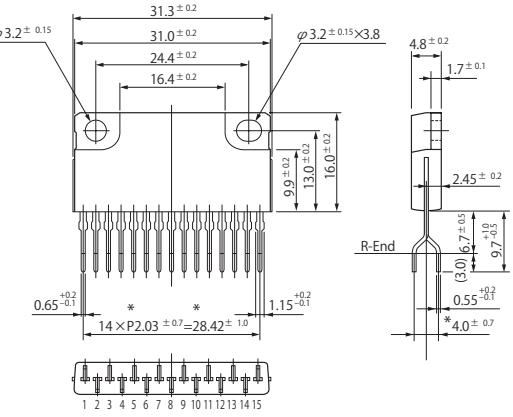
• SIP 15 (SMA15Pin)



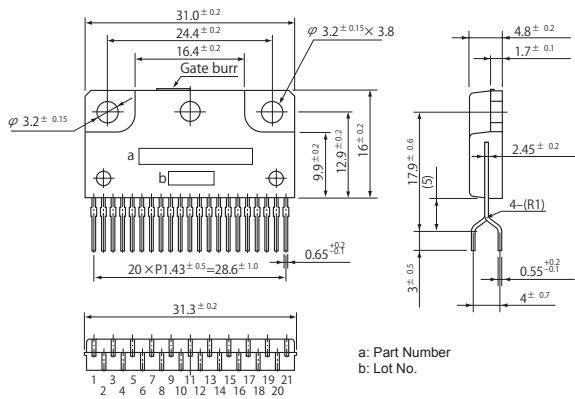
• SIP 12 with Fin (SLA12Pin)



• SIP 15 with Fin (SLA15Pin)



• SIP 21 with Fin (SLA21Pin)



(Unit:mm)